

3.3V CMOS OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS, 5 VOLT TOLERANT I/O, AND BUS-HOLD

IDT74LVCH2245A

FEATURES:

- 0.5 MICRON CMOS Technology
- ESD > 2000V per MIL-STD-883, Method 3015;
 - > 200V using machine model (C = 200pF, R = 0)
- 1.27mm pitch SOIC, 0.65mm pitch SSOP, 0.635mm pitch QSOP, 0.65mm pitch TSSOP packages
- Extended commercial range of 40°C to +85°C
- $VCC = 3.3V \pm 0.3V$, Normal Range
- Vcc = 2.3V to 3.6V, Extended Range
- CMOS power levels (0.4µW typ. static)
- Rail-to-Rail output swing for increased noise margin
- All inputs, outputs and I/O are 5 Volt tolerant
- Supports hot insertion

Drive Features for LVCH2245A:

Balanced Output Drivers: ±12mA (B port)
 High Output Drivers: ±24mA (A port)

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- Data communication and telecommunication systems

DESCRIPTION:

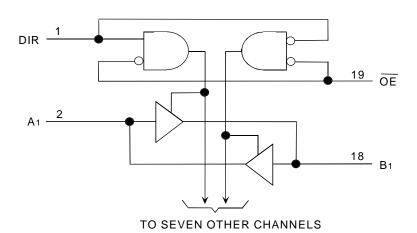
This bus transceiver is built using advanced dual metal CMOS technology. The LVCH2245A device is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable $(\overline{\text{OE}})$ input can be used to disable the device so the buses are effectively isolated.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V environment.

The LVCH2245A has series resistors in the output structure of the "B" port, which will significantly reduce line noise when used with light loads. The driver has been designed to drive ± 12 mA at the designated threshold levels. The "A" port has a ± 24 mA driver.

The LVCH2245A has "bus-hold" which retains the inputs' last state whenever the input goes to a high-impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

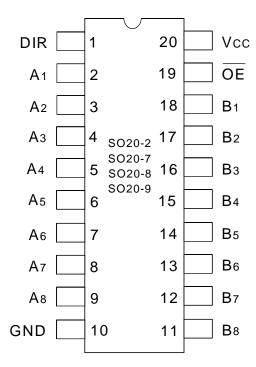
FUNCTIONAL BLOCK DIAGRAM



EXTENDED COMMERCIAL TEMPERATURE RANGE

OCTOBER 1999

PIN CONFIGURATION



SOIC/ SSOP/ QSOP/ TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS (1)

Symbol	Description	Max.	Unit
VTERM	Terminal Voltage with Respect to GND	- 0.5 to +6.5	V
Tstg	Storage Temperature	- 65 to +150	°C
lout	DC Output Current	- 50 to +50	mA
lik	Continuous Clamp Current,	- 50	mA
Іок	$V_I < 0$ or $V_O < 0$		
Icc	Continuous Current through	±100	mA
Iss	each Vcc or GND		8L V.C

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (TA = +25°C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	4.5	6	pF
Соит	Output Capacitance	Vout = 0V	5.5	8	pF
CI/O	I/O Port Capacitance	VIN = 0V	6.5	8	pF

NOTE:

1. As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description
ŌĒ	Output-enable Input (Active LOW)
xAx	Side A Inputs or 3-State Outputs (1)
хВх	Side B Inputs or 3-State Outputs (1)
DIR	Direction-control Input

NOTE:

 These pins have "Bus-hold". All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE (1)

Inputs		Outputs
ŌĒ	DIR	
L	L	B data to A bus
L	Н	A data to B bus
Н	Х	Isolation

NOTE:

H = HIGH Voltage Level
 L = LOW Voltage Level
 X = Don't Care

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = - 40°C To +85°C

Symbol	Parameter	-	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	٧
		Vcc = 2.7V to 3.6V		2	_	1]
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	_	0.7	٧
		Vcc = 2.7V to 3.6V		_	_	0.8	1
lih lil	Input Leakage Current	Vcc = 3.6V	VI = 0 to 5.5V	_	_	±5	μA
lozн	High Impedance Output Current	Vcc = 3.6V	Vo = 0 to 5.5V	_	_	±10	μA
lozl	(3-State Output pins)						
loff	Input/Output Power Off Leakage	Vcc = 0V, Vin or Vo	≤ 5.5V	_	_	±50	μA
Vik	Clamp Diode Voltage	Vcc = 2.3V, IiN = -1	8mA	_	- 0.7	- 1.2	٧
VH	Input Hysteresis	Vcc = 3.3V		_	100	_	mV
Iccl Icch	Quiescent Power Supply Current	Vcc = 3.6V	VIN = GND or Vcc	_	_	10	μA
Iccz			$3.6 \le VIN \le 5.5V^{(2)}$	_	_	10	1
ΔΙCC	Quiescent Power Supply Current Variation	One input at Vcc - 0. other inputs at Vcc c		_	_	500	μA 8LVC Link

NOTES

1. Typical values are at Vcc = 3.3V, +25°C ambient.

2. This applies in the disabled state only.

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Co	nditions	Min.	Typ. ⁽²⁾	Max.	Unit
Івнн	Bus-Hold Input Sustain Current	Vcc = 3.0V	VI = 2.0V	- 75		-	μA
IBHL			VI = 0.8V	75	_	_	
Івнн	Bus-Hold Input Sustain Current	Vcc = 2.3V	VI = 1.7V	_	_	_	μA
IBHL			VI = 0.7V	_	_	_	
Івнно	Bus-Hold Input Overdrive Current	Vcc = 3.6V	VI = 0 to 3.6V	_	_	± 500	μA
Івньо							

NOTES:

1. Pins with Bus-hold are identified in the pin description.

2. Typical values are at Vcc = 3.3V, +25°C ambient.

3.3V CMOS OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS

OUTPUT DRIVE CHARACTERISTICS FOR PORT A

Symbol	Parameter	Test Co	onditions ⁽¹⁾	Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	IOH = - 0.1mA	Vcc - 0.2	_	V
		Vcc = 2.3V	I _{OH} = -6mA	2	_	
		Vcc = 2.3V	IOH = - 12mA	1.7	_	
		Vcc = 2.7V		2.2	_	
		Vcc = 3.0V		2.4	_	
		Vcc = 3.0V	IOH = - 24mA	2.2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	_	0.2	V
		Vcc = 2.3V	IoL = 6mA	_	0.4	
			IoL = 12mA	_	0.7	
		Vcc = 2.7V	IoL = 12mA	_	0.4	
		Vcc = 3.0V	IoL = 24mA	_	0.55	
						8LVC Link

NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. Ta = − 40°C to +85°C.

OUTPUT DRIVE CHARACTERISTICS FOR PORT B

Symbol	Parameter	Test	Conditions ⁽¹⁾	Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	I _{OH} = -0.1mA	Vcc - 0.2	_	V
		Vcc = 2.3V	IOH = -4mA	1.9	_	
			IOH = -6mA	1.7	_	
		Vcc = 2.7V	IOH = -4mA	2.2	_	
			IOH = -8mA	2	_	
		Vcc = 3.0V	IOH = -6mA	2.4	_	
			IOH = - 12mA	2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	_	0.2	V
		Vcc = 2.3V	I _{OL} = 4mA	_	0.4	
			IoL = 6mA	_	0.55	
		Vcc = 2.7V	I _{OL} = 4mA	_	0.4	
			IoL = 8mA	_	0.6	
		Vcc = 3.0V	IoL = 6mA	_	0.55	
			I _{OL} = 12mA	_	0.8	1

NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = − 40°C to +85°C.

OPERATING CHARACTERISTICS, $V_{CC} = 3.3V \pm 0.3V$, $T_A = 25$ °C

Symbol	Parameter	Test Conditions	Typical	Unit
CPD	Power dissipation capacitance per tranceiver Outputs enabled	CL = 0pF, f = 10Mhz	48	pF
CPD	Power dissipation capacitance per tranceiver Outputs disabled		4	pF

SWITCHING CHARACTERISTICS (A PORT) (1)

		Vcc = 2.7V		Vcc = 3.3V±0.3V		
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tplh	Propagation Delay	_	7.3	1.5	6.3	ns
t PHL	xBx to xAx					
tpzh	Output Enable Time	_	9.5	1.5	8.5	no
tpzl	xOE to xAx					ns
tphz	Output Disable Time	_	8.5	1.7	7.5	no
tPLZ	x OE to xAx					ns
tsk(o)	Output Skew ⁽²⁾	_	_	_	500	ps

SWITCHING CHARACTERISTICS (B PORT)(1)

		Vcc = 2.7V		Vcc = 3.3V±0.3V			
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit	
tplh	Propagation Delay	_	8.1	1.5	7.1	ns	
tPHL	xAx to xBx						
tpzh	Output Enable Time	_	10	1.5	9		
tpzl	xOE to xBx					ns	
tphz	Output Disable Time	_	9.2	1.7	8.2		
tplz	xOE to xBx					ns	
tsk(o)	Output Skew ⁽²⁾	_	_	_	500	ps	

NOTES:

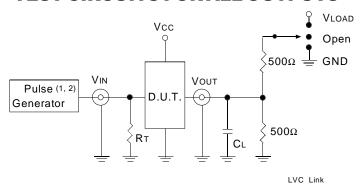
- 1. See test circuits and waveforms. $T_A = -40^{\circ}C$ to + 85°C.
- 2. Skew between any two outputs of the same package and switching in the same direction.

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$V_{CC}^{(1)} = 3.3V \pm 0.3V$	$V_{CC}^{(1)} = 2.7V$	$V_{CC}^{(2)} = 2.5V \pm 0.2V$	Unit
VLOAD	6	6	2 x Vcc	٧
VIH	2.7	2.7	Vcc	٧
VT	1.5	1.5	Vcc/2	٧
VLZ	300	300	150	mV
VHZ	300	300	150	mV
CL	50	50	30	pF

TEST CIRCUITS FOR ALL OUTPUTS



DEFINITIONS:

CL= Load capacitance: includes jig and probe capacitance.

 $\mathsf{RT} = \mathsf{Termination}$ resistance: should be equal to ZouT of the Pulse Generator.

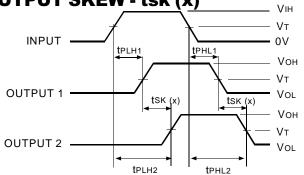
NOTES:

- 1. Pulse Generator for All Pulses: Rate ≤ 10MHz: tF ≤ 2.5ns: tR ≤ 2.5ns.
- 2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

Test	Switch
Open Drain	Vload
Disable Low	
Enable Low	
Disable High	GND
Enable High	
All Other tests	Open

OUTPUT SKEW - tsk (x)



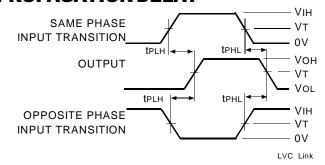
tsk(x) = |tPLH2 - tPLH1| or |tPHL2 - tPHL1|

NOTES:

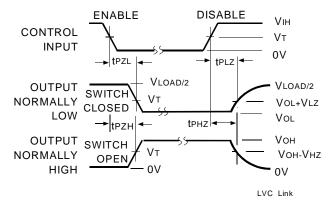
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- 1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
- 2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.

PROPAGATION DELAY



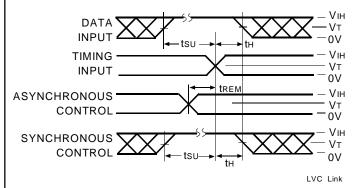
ENABLE AND DISABLE TIMES



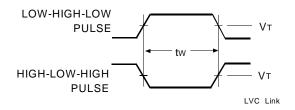
NOTE:

 Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

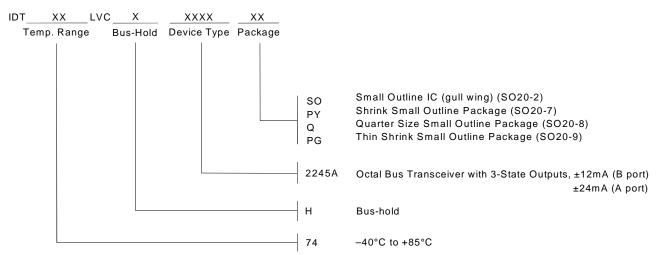
SET-UP, HOLD, AND RELEASE TIMES



PULSE WIDTH



ORDERING INFORMATION





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